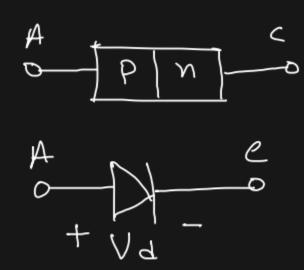
## Lecture 6

## Diodes



- Non-linear devices
- Electrical Valves: Permits current flow in one direction only
- Semiconductor devices, consists of a pn junction
- 2 terminals: Anode (A) and Cathode (C)
- Current flow direction: From Anode to Cathode
- Voltage across diode, Vd= Va- Vc; Where, Va= Anode voltage, Vc= Cathode voltage

$$\frac{DR}{-} Y = A + B$$

A B Y
O D
O
T
O
T

0 → Low State → 0V 1 → 416H " → 5V

Vp4	$V_{\mathbb{B}}$	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
0	O	
0	5	5
5	$\mathcal{O}$	5
5	5	5

0 R

Cincuit

Resistance, P -> Pull down registance

Care 2 Case 3  $O \rightarrow P_L$ D1:ON/F·B DI: OFF / R.B. D2: OFF I R.B D2: ON/F.B 5 - VY = 5 V

Truth Table

	A	B	*
	D	ට	0
١	0	(	O
_	ţ	D	Ò
	(	(	1

V <sub>A</sub>	\ \mathcal{S} \	ν,
O	O	70
0	5	0
5	0	0
5	5	5

Care 4 Cincuit Care 3 Case 2 Case 1 VB 2 BV, VA = 5V, NA = 13 = 21 VA - VB-01 VA -20 V V3 = 0V DI: OFF D. :ON/E.B. DIPN/EB. DIOFFIRB. D2:0FF D2: ON/F.B D2:0N DZ:OFF/2.8 Commode A - - - Vy VAZGV & VYZOV

B - - OV OU - - OV 5 v VAZOV } VB = 5 = 5V -- Vy 20V RzPall-up resistar

Different HIGH state voltages.

Four combinations:

1) 
$$D_1, D_2 \rightarrow X$$
  
2)  $D_1 \rightarrow X$ ,  $D_2 \rightarrow X$   
3)  $D_4 \rightarrow X$ ,  $D_2 \rightarrow X$   
4)  $D_1, D_2 \rightarrow X$ 

Four Si) DIID2 7x AND (ii) (ii) (ii) (ii) $D_1, D_2 \longrightarrow \sqrt{\phantom{a}}$ 

EXERCISE

i) AND, VA(HIGH) = 3V, VB(HIGH) = 1V, VCL = 3V 7

2) OR, VA(HIGH) = 3V, VB(HIGH) = 4V, VCL = 3V